

FEATURES

- Fast access time : 35/55/70ns
- Low power consumption:
 - Operating current : 40/35/30mA (TYP.)
 - Standby current : 2 μ A (TYP.) L-version
 - 1 μ A (TYP.) LL-version
- Single 5V power supply
- All inputs and outputs TTL compatible
- Fully static operation
- Tri-state output
- Data retention voltage : 2.0V (MIN.)
- Package : 28-pin 600 mil PDIP
 - 28-pin 330 mil SOP
 - 28-pin 8mm x 13.4mm STSOP

GENERAL DESCRIPTION

The LY62256 is a 262,144-bit low power CMOS static random access memory organized as 32,768 words by 8 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

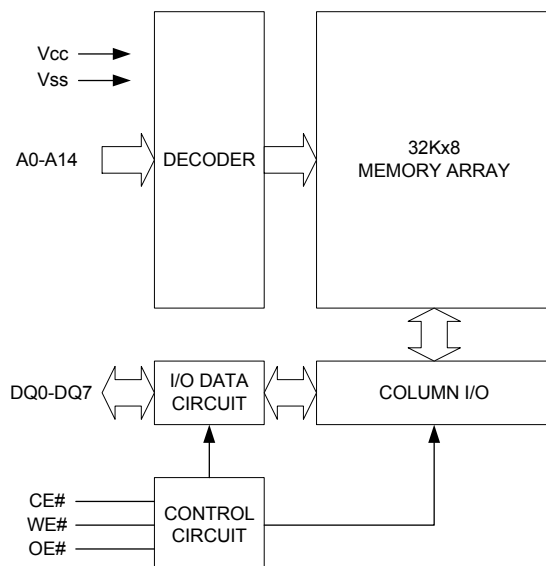
The LY62256 is well designed for low power application, and particularly well suited for battery back-up nonvolatile memory application.

The LY62256 operates from a single power supply of 5V and all inputs and outputs are fully TTL compatible

PRODUCT FAMILY

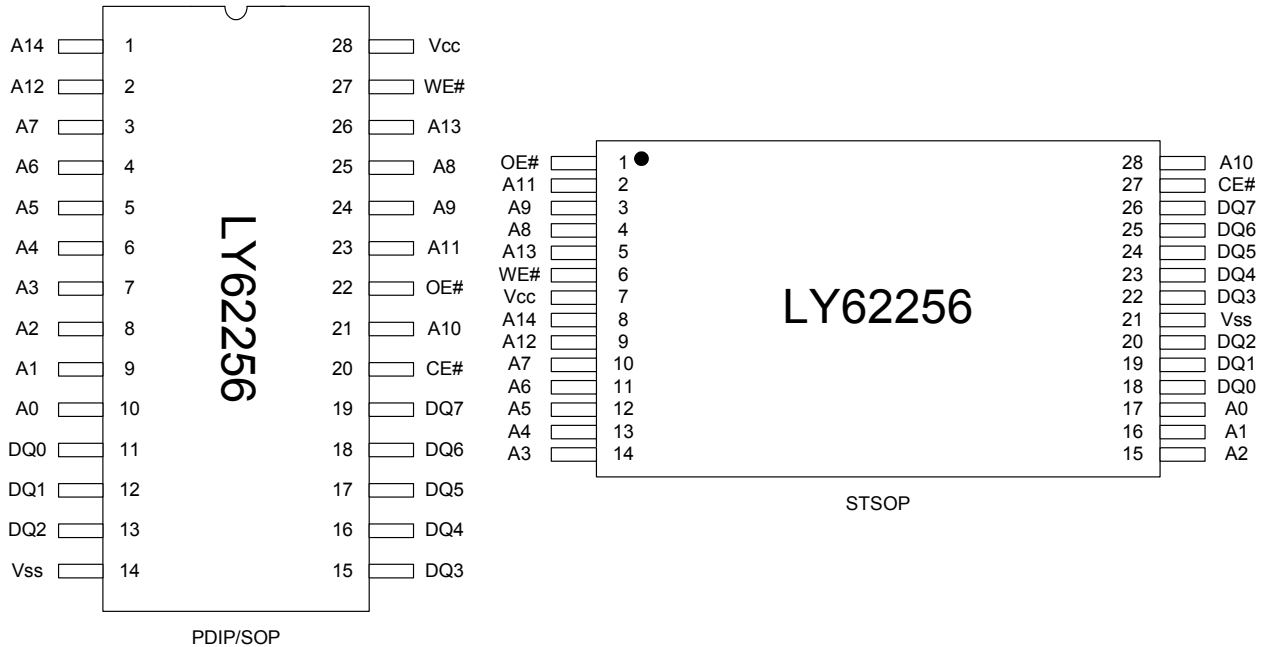
Product Family	Operating Temperature	Vcc Range	Speed	Power Dissipation	
				Standby(I _{SB1} , TYP.)	Operating(I _{CC} , TYP.)
LY62256	0 ~ 70°C	4.5 ~ 5.5V	35/55/70ns	2 μ A(L)/1 μ A(LL)	40/35/30mA
LY62256(E)	-20 ~ 80°C	4.5 ~ 5.5V	35/55/70ns	2 μ A(L)/1 μ A(LL)	40/35/30mA
LY62256(I)	-40 ~ 85°C	4.5 ~ 5.5V	35/55/70ns	2 μ A(L)/1 μ A(LL)	40/35/30mA

FUNCTIONAL BLOCK DIAGRAM



PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0 - A14	Address Inputs
DQ0 - DQ7	Data Inputs/Outputs
CE#	Chip Enable Input
WE#	Write Enable Input
OE#	Output Enable Input
Vcc	Power Supply
Vss	Ground

PIN CONFIGURATION

ABSOLUTE MAXIMUM RATINGS*

PARAMETER	SYMBOL	RATING	UNIT
Terminal Voltage with Respect to Vss	V _{TERM}	-0.5 to 7.0	V
Operating Temperature	T _A	0 to 70(C grade)	°C
		-20 to 80(E grade)	
		-40 to 85(I grade)	
Storage Temperature	T _{STG}	-65 to 150	°C
Power Dissipation	P _D	1	W
DC Output Current	I _{OUT}	50	mA
Soldering Temperature (under 10 sec)	T _{SOLDER}	260	°C

*Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

TRUTH TABLE

MODE	CE#	OE#	WE#	I/O OPERATION	SUPPLY CURRENT
Standby	H	X	X	High-Z	I _{SB} , I _{SB1}
Output Disable	L	H	H	High-Z	I _{CC} , I _{CC1}
Read	L	L	H	D _{OUT}	I _{CC} , I _{CC1}
Write	L	X	L	D _{IN}	I _{CC} , I _{CC1}

Note: H = V_{IH}, L = V_{IL}, X = Don't care.

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. ⁵	MAX.	UNIT	
Supply Voltage	V _{CC}		4.5	5.0	5.5	V	
Input High Voltage	V _{IH} ¹		2.4	-	V _{CC} +0.5	V	
Input Low Voltage	V _{IL} ²		- 0.5	-	0.8	V	
Input Leakage Current	I _{LI}	V _{CC} ≥ V _{IN} ≥ V _{SS}	- 1	-	1	μA	
Output Leakage Current	I _{LO}	V _{CC} ≥ V _{OUT} ≥ V _{SS} , Output Disabled	- 1	-	1	μA	
Output High Voltage	V _{OH}	I _{OH} = -1mA	2.4	-	-	V	
Output Low Voltage	V _{OL}	I _{OL} = 2mA	-	-	0.4	V	
Average Operating Power supply Current	I _{CC}	Cycle time = Min. CE# = V _{IL} , I _{I/O} = 0mA	-35	-	40	50	mA
			-55	-	35	45	mA
			-70	-	30	40	mA
	I _{CC1}	Cycle time = 1μs CE# ≤ 0.2V and I _{I/O} = 0mA other pins at 0.2V or V _{CC} -0.2V	-	5	10	mA	
Standby Power Supply Current	I _{SB}	CE# = V _{IH}	-	1	3	mA	
	I _{SB1}	CE# ≥ V _{CC} - 0.2V	-L	-	2	100	μA
			-LL	-	1	50 ⁴	μA

Notes:

- V_{IH}(max) = V_{CC} + 3.0V for pulse width less than 10ns.
- V_{IL}(min) = V_{SS} - 3.0V for pulse width less than 10ns.
- Over/Undershoot specifications are characterized, not 100% tested.
- 10μA for special request
- Typical values are included for reference only and are not guaranteed or tested.
Typical valued are measured at V_{CC} = V_{CC}(TYP.) and T_A = 25°C

CAPACITANCE (T_A = 25°C, f = 1.0MHz)

PARAMETER	SYMBOL	MIN.	MAX	UNIT
Input Capacitance	C _{IN}	-	6	pF
Input/Output Capacitance	C _{I/O}	-	8	pF

Note : These parameters are guaranteed by device characterization, but not production tested.

AC TEST CONDITIONS

Input Pulse Levels	0.2V to V _{CC} - 0.2V
Input Rise and Fall Times	3ns
Input and Output Timing Reference Levels	1.5V
Output Load	C _L = 50pF + 1TTL, I _{OH} /I _{OL} = -1mA/2mA



AC ELECTRICAL CHARACTERISTICS

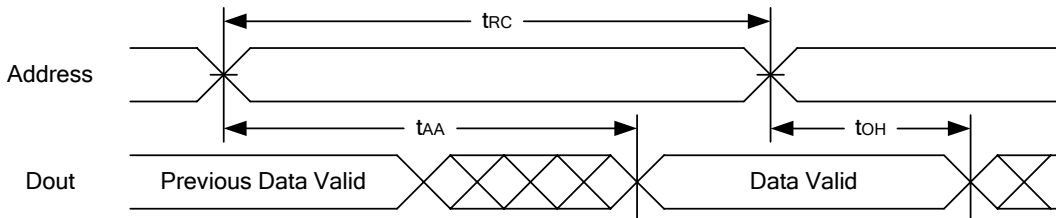
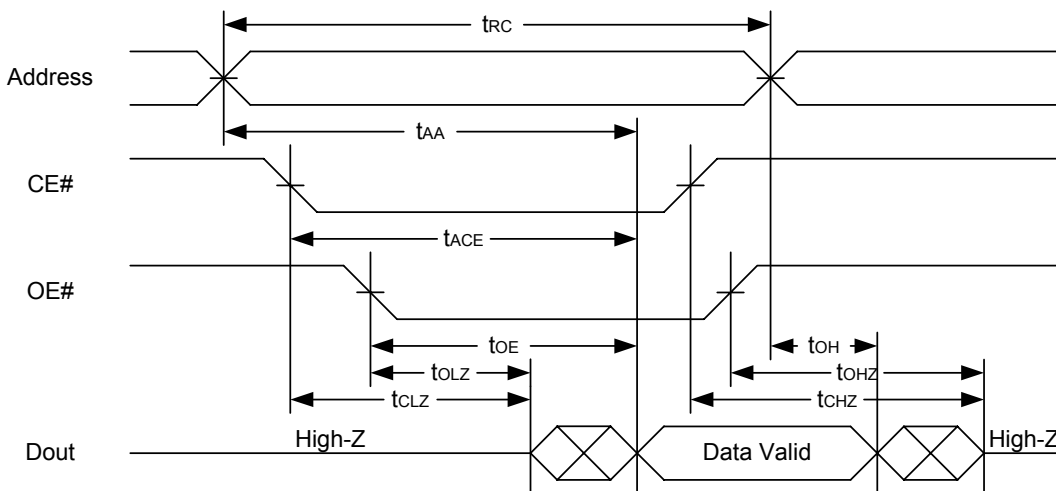
(1) READ CYCLE

PARAMETER	SYM.	LY62256-35		LY62256-55		LY62256-70		UNIT
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Read Cycle Time	t _{RC}	35	-	55	-	70	-	ns
Address Access Time	t _{AA}	-	35	-	55	-	70	ns
Chip Enable Access Time	t _{ACE}	-	35	-	55	-	70	ns
Output Enable Access Time	t _{OE}	-	25	-	30	-	35	ns
Chip Enable to Output in Low-Z	t _{CLZ} *	10	-	10	-	10	-	ns
Output Enable to Output in Low-Z	t _{OLZ} *	5	-	5	-	5	-	ns
Chip Disable to Output in High-Z	t _{CHZ} *	-	15	-	20	-	25	ns
Output Disable to Output in High-Z	t _{OHZ} *	-	15	-	20	-	25	ns
Output Hold from Address Change	t _{OH}	10	-	10	-	10	-	ns

(2) WRITE CYCLE

PARAMETER	SYM.	LY62256-35		LY62256-55		LY62256-70		UNIT
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Write Cycle Time	t _{WC}	35	-	55	-	70	-	ns
Address Valid to End of Write	t _{AW}	30	-	50	-	60	-	ns
Chip Enable to End of Write	t _{CW}	30	-	50	-	60	-	ns
Address Set-up Time	t _{AS}	0	-	0	-	0	-	ns
Write Pulse Width	t _{WP}	25	-	45	-	55	-	ns
Write Recovery Time	t _{WR}	0	-	0	-	0	-	ns
Data to Write Time Overlap	t _{DW}	20	-	25	-	30	-	ns
Data Hold from End of Write Time	t _{DH}	0	-	0	-	0	-	ns
Output Active from End of Write	t _{OW} *	5	-	5	-	5	-	ns
Write to Output in High-Z	t _{WHZ} *	-	15	-	20	-	25	ns

*These parameters are guaranteed by device characterization, but not production tested.

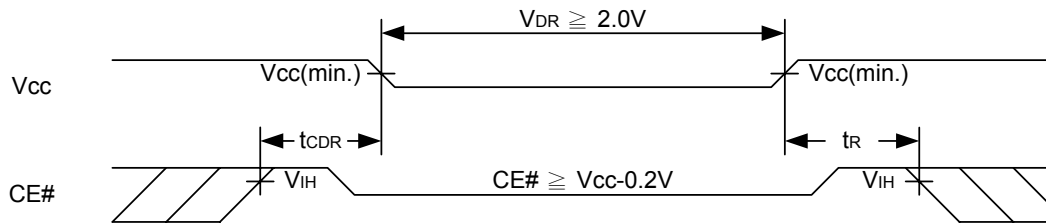
TIMING WAVEFORMS
READ CYCLE 1 (Address Controlled) (1,2)

READ CYCLE 2 (CE# and OE# Controlled) (1,3,4,5)

Notes :

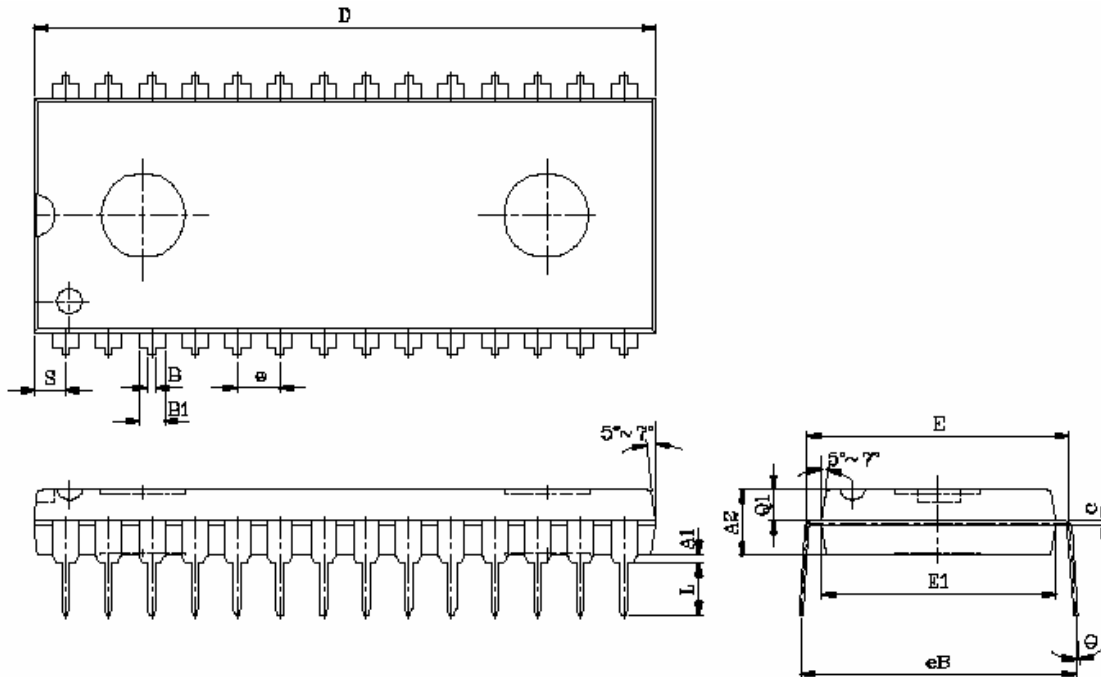
1. WE# is high for read cycle.
2. Device is continuously selected OE# = low, CE# = low.
3. Address must be valid prior to or coincident with CE# = low,; otherwise tAA is the limiting parameter.
4. tCLZ, tOLZ, tCHZ and tOHZ are specified with CL = 5pF. Transition is measured ±500mV from steady state.
5. At any given temperature and voltage condition, tCHZ is less than tCLZ, tOHZ is less than tOLZ.

DATA RETENTION CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
V _{CC} for Data Retention	V _{DR}	CE# \geq V _{CC} - 0.2V	2.0	-	5.5	V	
Data Retention Current	I _{DR}	V _{CC} = 2.0V CE# \geq V _{CC} - 0.2V	-L	-	1	50	μ A
			-LL	-	0.5	20	μ A
Chip Disable to Data Retention Time	t _{CDR}	See Data Retention Waveforms (below)	0	-	-	ns	
Recovery Time	t _R		t _{RC*}	-	-	ns	

 *t_{RC} = Read Cycle Time

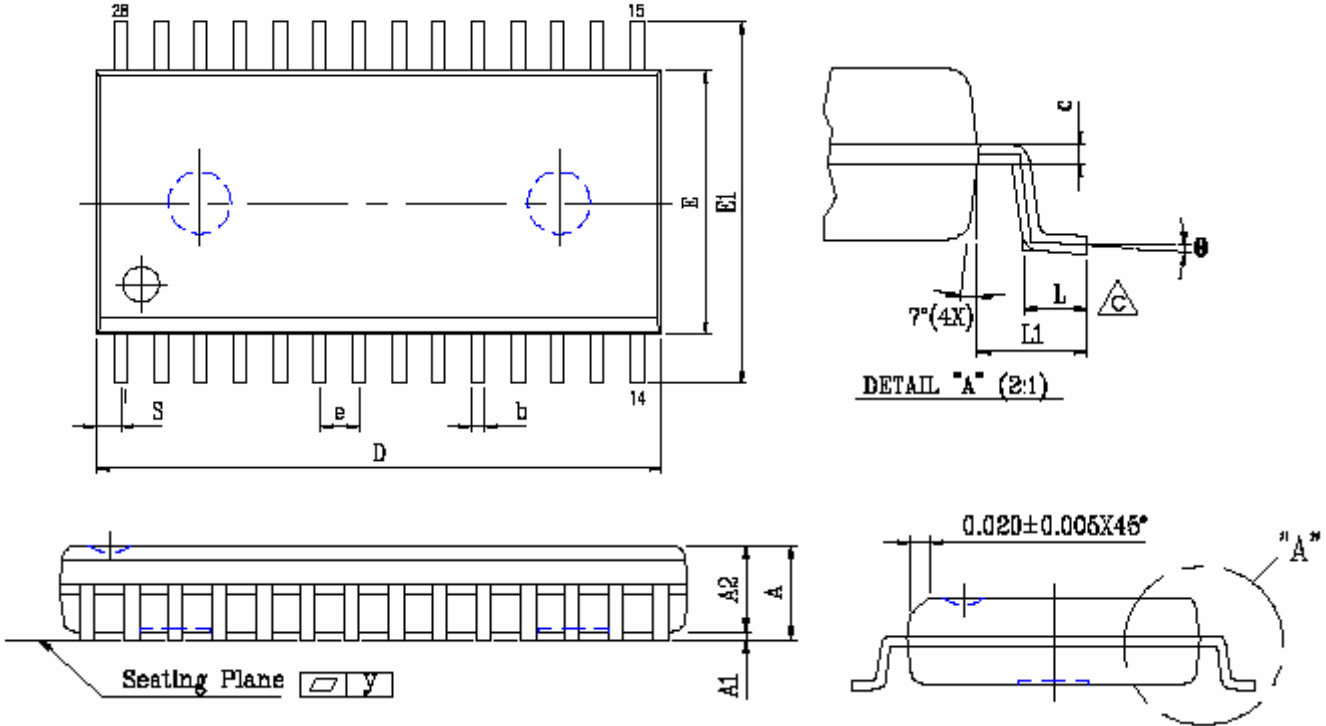
DATA RETENTION WAVEFORM


PACKAGE OUTLINE DIMENSION
28 pin 600 mil PDIP Package Outline Dimension


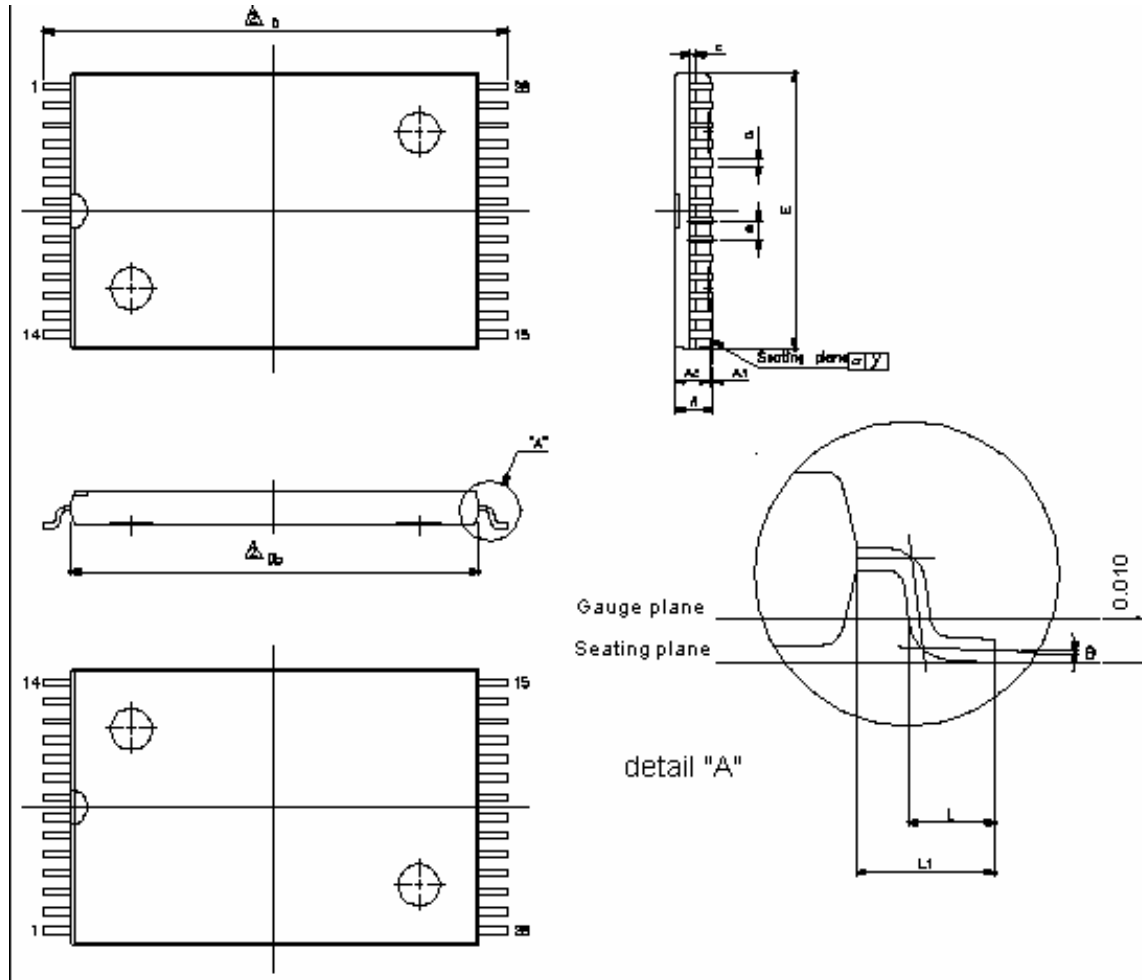
SYM.	UNIT	INCH.(BASE)	MM(REF)
A1		0.010 (MIN)	0.254 (MIN)
A2		0.150±0.005	3.810±0.127
B		0.020 (MAX)	0.508(MAX)
B1		0.055 (MAX)	1.397(MAX)
c		0.012 (MAX)	0.304 (MAX)
D		1.430 (MAX)	36.322 (MAX)
E		0.6 (TYP)	15.24 (TYP)
E1		0.52 (MAX)	13.208 (MAX)
e		0.100 (TYP)	2.540(TYP)
eB		0.625 (MAX)	15.87 (MAX)
L		0.180(MAX)	4.572(MAX)
S		0.06 (MAX)	1.524 (MAX)
Q1		0.08(MAX)	2.032(MAX)
Θ		15°(MAX)	15°(MAX)



28 pin 330 mil SOP Package Outline Dimension



SYM.	UNIT	
	INCH(BASE)	MM(REF)
A	0.120 (MAX)	3.048 (MAX)
A1	0.002(MIN)	0.05(MIN)
A2	0.098±0.005	2.489±0.127
b	0.016 (TYP)	0.406(TYP)
c	0.010 (TYP)	0.254(TYP)
D	0.728 (MAX)	18.491 (MAX)
E	0.340 (MAX)	8.636 (MAX)
E1	0.465±0.012	11.811±0.305
e	0.050 (TYP)	1.270(TYP)
L	0.05 (MAX)	1.270 (MAX)
L1	0.067±0.008	1.702 ±0.203
S	0.047 (MAX)	1.194 (MAX)
y	0.003(MAX)	0.076(MAX)
θ	0°~10°	0°~10°

28 pin 8mm x 13.4mm STSOP Package Outline Dimension


SYM.	UNIT	INCH(BASE)	MM(REF)
A		0.047 (MAX)	1.20 (MAX)
A1		0.004±0.002	0.10±0.05
A2		0.039±0.002	1.00±0.05
b		0.006 (TYP)	0.15(TYP)
c		0.010 (TYP)	0.254(TYP)
D_b		0.465±0.004	11.80±0.10
E		0.315±0.004	8.00±0.10
e		0.022 (TYP)	0.55(TYP)
D		0.528±0.008	13.40±0.20
L		0.020±0.004	0.50±0.10
L1		0.0315±0.004	0.80±0.10
y		0.08(MAX)	0.003(MAX)
Θ		0°~5°	0°~5°

Note : E dimension is not including end flash. The total of both sides' end flash is not above 0.3mm.



ORDERING INFORMATION

LY62256 V W - XX YY Z

Z : Temperature Range
Blank : (Commercial) 0°C ~ 70°C
E : (Extended) -20°C ~ +80°C
I : (Industrial) -40°C ~ +85°C

YY : Power Type
L : Low Power
LL : Ultra Low Power

XX : Access Time(Speed)

W : Lead Information
N : Normal
L : Lead Free

V : Package Type
P : 28-pin 600 mil P-DIP
S : 28-pin 330 mil SOP
R : 28-pin 8 mm x 13.4 mm STSOP

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